Unit: mm

0.7±0.1

2.0±0.1

(0.65)(0.65)

Schottky Barrier Diodes (SBD)

MA6J784

Silicon epitaxial planar type

For super high speed switching For small current rectification

Features

- $I_{F(AV)} = 100$ mA rectification is possible
- Optimum for high frequency rectification because of its short reverse recovery time (t_{rr})
- Low forward voltage V_F and good rectification efficiency

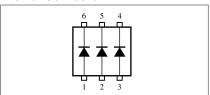
■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	30	V
Repetitive peak reverse voltage	V_{RRM}	30	V
Average forward current *2	I _{F(AV)}	100	mA
Peak forward current *2	I_{FM}	300	mA
Non-repetitive peak forward surge current *1, 2	I _{FSM}	1	A
Junction temperature	T _j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Note) *1: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

*2: Value of each diode in double diodes used.

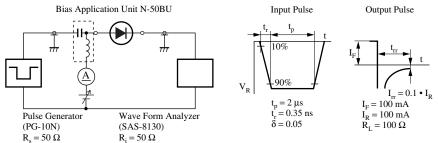
1: Anode 1 2: Anode 2 5: Cathode 2 3: Anode 3 6: Cathode 1 EIAJ: SC-88 SMini6-F1 Package Marking Symbol: M8A Internal Connection

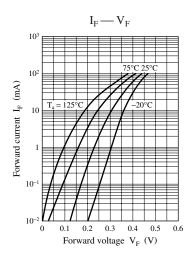


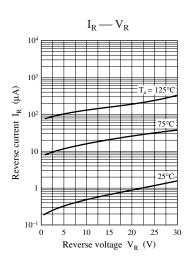
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

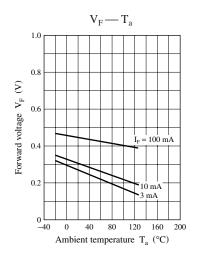
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _F	$I_F = 100 \text{ mA}$			0.55	V
Reverse current	I_R	$V_R = 30 \text{ V}$			15	μΑ
Terminal capacitance	Ct	$V_R = 0 \text{ V, } f = 1 \text{ MHz}$		20		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 100 \text{ mA}$		2.0		ns
		$I_{rr} = 0.1 \cdot I_R$, $R_L = 100 \Omega$				

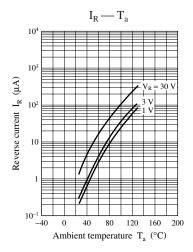
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. Rated input/output frequency: 250 MHz
 - 4. *: t_{rr} measuring instrument

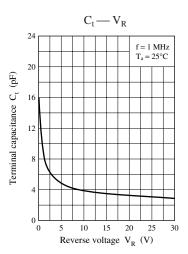












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